The listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1.-3. (Canceled)

4. (Currently Amended) A semiconductor device comprising:

a support which is an adhesive material substrate;

an adhesive material over the substrate;

a protective film over the support adhesive material;

an insulating film over the protective film; and

a middle processing component comprising a control section and an operation section, and a memory unit over the insulating film,

wherein the middle processing component includes a thin film transistor of nchannel type and a thin film transistor of p-channel type.

5. (Currently Amended) A semiconductor device according to any one of claims 1, 2, or 4 claim 4, wherein the semiconductor device is an authentication card, a video camera, a digital camera, a goggle type display, a car navigation system, a personal computer, or a mobile information terminal.

6.-19. (Canceled)

- 20. (Currently Amended) A semiconductor device comprising:
- a first protective film a substrate;
- a thin film transistor over the first protective film;

a support which is an adhesive material over the thin-film transistor substrate; and

a second protective film over the support adhesive material;

an insulating film over the protective film;

a middle processing component comprising a control section and an operation section, and a memory unit over the insulating film; and

a battery over the substrate;

wherein the middle processing component includes a thin film transistor of nchannel type and a thin film transistor of p-channel type.

21.-27. (Canceled)

28. (New) A semiconductor device comprising:

a plastic substrate;

an adhesive material over the plastic substrate; and

a protective film over the adhesive material, said protective film comprising a material selected from the group consisting of SnO₂, SrO, Teflon, and metal;

an insulating film over the protective film, said insulating film comprising silicon oxynitride;

a middle processing component comprising a control section and an operation section, and a memory unit over the insulating film; and

a battery over the plastic substrate;

wherein the middle processing component includes a thin film transistor of nchannel type and a thin film transistor of p-channel type.

29. (New) A semiconductor device comprising:

a plastic substrate;

an adhesive material over the plastic substrate; and

a protective film over the adhesive material, said protective film comprising a material selected from the group consisting of SnO₂, SrO, Teflon, and metal;

an insulating film over the protective film;

a middle processing component comprising a control section and an operation section, and a memory unit over the insulating film; and

wherein the middle processing component includes a thin film transistor of nchannel type and a thin film transistor of p-channel type.

- A semiconductor device according to claim 28, wherein the 30. semiconductor device is an authentication card, a video camera, a digital camera, a goggle type display, a car navigation system, a personal computer, or a mobile information terminal.
- A semiconductor device according to claim 29, wherein the 31. semiconductor device is an authentication card, a video camera, a digital camera, a goggle type display, a car navigation system, a personal computer, or a mobile information terminal.